IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

re Patent Application of:

ZENG

09/844,347 Serial No.

Confirmation No. 2463

Filing Date: April 27, 2001

For: POWER MOSFET AND METHOD FOR

FORMING SAME USING A SELF-

ALIGNED BODY IMPLANT

Examiner: I. SOWARD

Art Unit: 2822

AMENDMENT

Director, U.S. Patent and Trademark Office Washington, D.C. 20231

Sir:

Responsive to the Official Action of March 26, 2002, please enter the amendments and remarks set out below.

In the Drawings:

Submitted herewith is a request for a proposed drawing modification as indicated in red ink to change a reference label in FIG. 2. A new drawing figure (FIG. 16) is also being submitted. No new matter is being added.

In the Specification:

Please insert the following paragraph on page 6, between line 31, and page 7, line 1:

-- FIG. 16 is a top plan view of the trench-gated power MOSFET according to the present invention. --